NSN 5961-01-353-6220

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-353-6220 **Inclosure Material:** Plastic or ceramic **Overall Length:** Between 0.645 inches and 0.665 inches **Terminal Length:** Between 0.500 inches and 0.750 inches **Overall Height:** Between 0.190 inches and 0.200 inches **Overall Width:** Between 0.410 inches and 0.420 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 reverse voltage, peak **Current Rating Per Characteristic:** 12.00 amperes source cutoff current preset and 100.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No